

CS2N65A3R 华润华晶CRMICRO

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| 产品名称 | CS2N65A3R 华润华晶CRMICRO |
| 公司名称 | 深圳市飞捷士科技有限公司 |
| 价格 | .65/个 |
| 规格参数 | Vds:650V Id:2A Rds:4.2 |
| 公司地址 | 深圳市龙华区民治街道龙胜路融创智汇大厦C座 1306-1307 |
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产品详情

Silicon N-Channel Power MOSFET CS2N65A3R

General Description :

CS2N65 A3R, the silicon N-channel Enhanced VDMOSFETs, is obtained by the self-aligned planar Technology which reduce the conduction loss, improve switching performance and enhance the avalanche energy. The transistor can be used in various power switching circuit for system miniaturization and higher efficiency. The package form is TO-251, which accords with the RoHS standard.

Features :

Fast Switching

Low ON Resistance($R_{dson} \leq 5$)

Low Gate Charge (Typical Data: 9.5nC)

Low Reverse transfer capacitances(Typical:3pF)

100% Single Pulse avalanche energy Test

Applications :

Power switch circuit of adaptor and charger.